NSN 5961-01-041-6809

Transistor - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

Between 0.170 inches and 0.210 inches

Terminal Length:

0.500 inches

Overall Diameter:

Between 0.209 inches and 0.230 inches

Internal Configuration:

Field effect

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

20.0 drain to source voltage and 40.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 40.0

breakdown voltage, gate-to-source, with all other terminals short-circuited to source

Current Rating Per Characteristic:

50.00 milliamperes drain current and 50.00 milliamperes gate current

Power Rating Per Characteristic:

300.0 milliwatts total device dissipation

Terminal Type And Quantity:

4 uninsulated wire lead

Specification Data:

80131-release5609 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0